

SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

LV8405V — ^{Bi-CMOS IC} 2ch Forward/Reverse Motor Driver

Overview

LV8405T is a 2ch forward/reverse motor driver IC using D-MOS FET for output stage. As MOS circuit is used, it supports the PWM input. Its features are that the on resistance $(0.75\Omega \text{ typ})$ and current dissipation are low.

It also provides protection functions such as heat protection circuit and reduced voltage detection and is optimal for the motors that need high-current.

Functions

- 2ch forward/reverse motor driver.
- Low power consumption.
- Low-temperature resistance 0.75Ω .

- Built-in low voltage reset and thermal shutdown circuit.
- Four mode function forward/reverse, brake, stop.
- Built-in charge pump.

Specifications

Maximum Ratings at $Ta = 25^{\circ}C$, SGND = PGND = 0V

Parameter	Symbol	Conditions	Ratings	Unit
Power supply voltage (for load)	VM max		-0.5 to 16.0	V
Power supply voltage (for control)	V _{CC} max		-0.5 to 6.0	V
Output current	I _O max		1.4	А
Output peak current	I _O peak	$t \leq 10ms$	2.5	А
Input voltage	V _{IN} max		-0.5 to V _{CC} +0.5	V
Allowable power dissipation	Pd max	Mounted on a specified board*	800	mW
Operating temperature	Topr		-30 to +85	°C
Storage temperature	Tstg		-55 to +150	°C

* Specified board : 114.3mm \times 76.1mm \times 1.6mm, glass epoxy board.

Caution 1) Absolute maximum ratings represent the value which cannot be exceeded for any length of time.

Caution 2) Even when the device is used within the range of absolute maximum ratings, as a result of continuous usage under high temperature, high current, high voltage, or drastic temperature change, the reliability of the IC may be degraded. Please contact us for the further details.

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Allowable Operating Conditions at Ta = 25°C, SGND = PGND = 0V

Parameter	Symbol	Conditions	Ratings	Unit
Power supply voltage (VM pin)	VM		1.5 to 15.0	V
Power supply voltage (V _{CC} pin)	VCC		2.8 to 5.5	V
Input signal voltage	VIN		0 to V _{CC}	V
Input signal frequency	f max		200	kHz

Electrical Characteristics Ta = 25° C, V_{CC} = 3.0V, VM = 6.0V, SGND = PGND = 0V, unless otherwise specified.

Parameter		0				Ratings		Unit
		Symbol	Conditions Remarks		min	typ	max	Unit
Standby load current drain		IMO	$V_{CC} = 0V, VM = 6V$	1			1.0	μΑ
Operating contr	ol current drain	IC1	When V_{CC} is applied, with no load	2		0.85	1.2	mA
High-level input	voltage	VIH	$2.7 \leq V_{CC} \leq 5.5 V$		0.6×V _{CC}		VCC	V
Low-level input	voltage	VIL	$2.7 \leq V_{CC} \leq 5.5 V$		0		0.2×V _{CC}	V
High-level input (IN1, IN2, IN3, I		IIH	IN1, IN2, IN3, IN4 = 3V	3		15	25	μΑ
Low-level input current (IN1, IN2, IN3, IN4)		IIL	IN1, IN2, IN3, IN4 = 0V	3	-1.0			μΑ
Pull-down resistance value (IN1-4)		RPD1			100	200	400	kΩ
Charge pump voltage		VG	V _{CC} + VM		8.5	9.0	9.5	V
Output ON resistance 1		RON1	Sum of top and bottom sides ON resistance.	4		0.75	1.2	Ω
Output ON resistance 2		RON2	Sum of top and bottom sides ON resistance. $V_{CC} = 2.8V$	4		1.0	1.5	Ω
Low-voltage detection voltage		VCS	V _{CC} pin voltage is monitored	5	2.15	2.30	2.45	V
Thermal shutdown temperature		Tth	Design guarantee value *	6	150	180	210	°C
Output block	Turn-on time	TPLH		7		0.2	0.4	μS
	Turn-off time	TPHL		7		0.2	0.4	μS

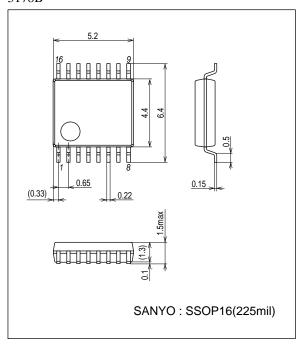
* : Design guarantee value and no measurement is preformed.

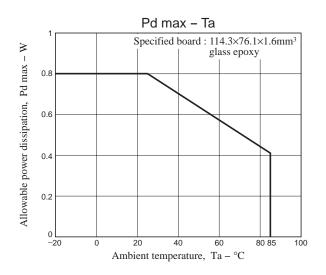
Remarks

- 1. Current consumption when output at the VM pin is off.
- 2. Current consumption at the V_{CC} pin when V_{CC} is 3V and IN1 to IN4 are all 0V (standby mode).
- 3. Pins IN 1, 2, 3, and 4 are all pulled down.
- 4. Sum of upper and lower saturation voltages of OUT pin divided by the current.
- 5. All power transistors are turned off if a low V_{CC} condition is detected.
- 6. All output transistors are turned off if the thermal protection circuit is activated. They are turned on again as the temperature goes down.
- 7. Rising time from 10 to 90% and falling time from 90 to 10% are specified.

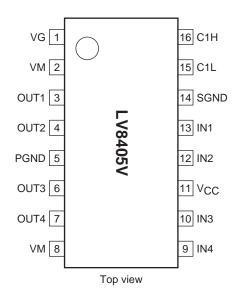
Package Dimensions

unit : mm (typ) 3178B

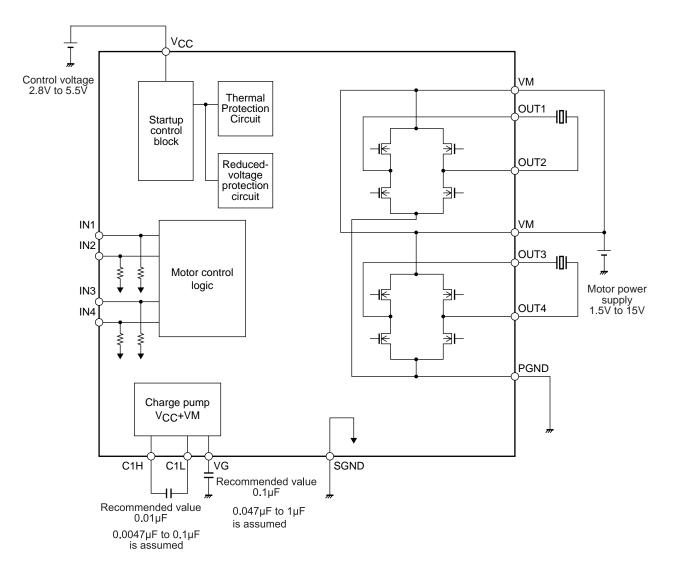




Pin Assignment



Block Diagram



* Connect a kickback absorption capacitor as near as possible to the IC. Coil kickback may cause increase in VM line voltage, and a voltage exceeding the maximum rating may be applied momentarily to the IC, which results in deterioration or damage of the IC

Truth Table

IN1 (IN3)	IN2 (IN4)	OUT1 (OUT3)	OUT2 (OUT4)	Charge pump	Mode
н	Н	Z	Z	ON	Standby
н	L	L	н		Reverse
L	Н	н	L		Forward
L	L	L	L		Brake

- : denotes a don't care value. Z : High-impedance

 \bullet The charge pump is always activated as long as $V_{\mbox{CC}}$ is applied.

* All power transistors turn off and the motor stops driving when the IC is detected in low voltage or thermal protection mode.

<mark>in F</mark> ur	octions		
Pin No.	Pin name	Description	Equivalent circuit
16 1	C1H VG	Step-up capacitor connection pin.	C1H
13	IN1	Driver output switching.	V _{CC}
12	IN2	(Pull-down resistor incorporated)	
10	IN3		
9	IN4		→ → → → → → → → → → → → → → → → → → →
3 4 7	OUT1 OUT2 OUT3 OUT4	Driver output.	
2	VM	Motor block power supply.	PGND
8 11	V.c	Logic block power supply.	
11	V _{CC} SGND	Control block ground.	
5	PGND	Driver block ground.	

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